



### 55GN01CA-TB-E Information



For Reference Only

Part Number 55GN01CA-TB-E Manufacturer ON Semiconductor

Category Discrete Semiconductor Products
Transistors - Bipolar (BJT) - RF

**Description** TRANS NPN BIPOLAR 10V 70MA CP

**Package** TO-236-3, SC-59, SOT-23-3

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

# **Certified Quality**

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









## 55GN01CA-TB-E Specifications

Manufacturer Part Number	55GN01CA-TB-E
Manufacturer	ON Semiconductor
Category	Discrete Semiconductor Products
	Transistors - Bipolar (BJT) - RF
Package	TO-236-3, SC-59, SOT-23-3
Series	-
Transistor Type	NPN
Voltage - Collector Emitter Breakdown (Max)	10V
Frequency - Transition	4.5GHz
Noise Figure (dB Typ @ f)	1.9dB @ 1GHz
Gain	9.5dB
Power - Max	200mW
DC Current Gain (hFE) (Min) @ Ic, Vce	100 @ 10mA, 5V
Current - Collector (Ic) (Max)	70mA
Operating Temperature	150°C (TJ)
Mounting Type	Surface Mount
Package / Case	TO-236-3, SC-59, SOT-23-3
Supplier Device Package	3-CP
	Report errors?

#### **55GN01CA-TB-E Guarantees**



#### **Quality Guarantees**

We provide 90 days warranty. \*

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



#### **Service Guarantees**

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

### 55GN01CA-TB-E Payment Methods



















### 55GN01CA-TB-E Shipping Methods













If you have any question about 55GN01CA-TB-E, please do not hesitate to contact us!

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